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Two-dimensional magnetic metal–organic frameworks with the Shastry–Sutherland lattice†

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Inspired by the successful synthesis of Fe/Cu-5,5'-bis(4-pyridyl)(2,2'-bipiridine) (PBP), a family of two-dimensional (2D) metal–organic frameworks (MOFs) with the Shastry–Sutherland lattice, *i.e.*, transition metal (TM)-PBP (TM = Cr, Mn, Fe, Co, Ni, Cu, Zn) has been systematically investigated by means of first-principles density functional theory calculations and Monte Carlo simulations. Mn-PBP is discovered to be the first ferromagnetic 2D MOF with the Shastry–Sutherland lattice and the Curie temperature is predicted to be about 105 K, while Fe-PBP, TM-PBP (TM = Cr, Co, Ni) and TM-PBP (TM = Cu, Zn) are found to be stripe-order antiferromagnetic, magnetic-dimerized and nonmagnetic, respectively. The electronic structure calculations reveal that TM-PBP MOFs are semiconductors with band gaps ranging from 0.12 eV to 0.85 eV, which could be easily modulated by various methods. Particularly, Mn-PBP would exhibit half-metallic behavior under compressive strain or appropriate electron/hole doping and a Mn-PBP based spintronic device has been proposed. This study not only improves the understanding of the geometric, electronic and magnetic properties of the 2D TM-PBP MOF family, but also provides a novel spin lattice playground for the research of 2D magnetic systems, which has diverse modulating possibilities and rich potential applications.

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Introduction

Two-dimensional (2D) metal–organic frameworks (MOFs)^{1–5} are novel 2D materials formed by metal atoms and polar organic molecules, and have aroused wide interest among researchers^{6–16} due to their advantages of low cost, chemical tenability, easy fabrication, and mechanical flexibility. Novel physical properties, such as ferromagnetic/antiferromagnetic ground states,^{17–20} superconductivity,²¹ and topological

insulation,^{22–24} have also been discovered in 2D MOF systems. According to their geometrical structure, the lattice structures of 2D MOFs can be classified into hexagonal lattice,^{20,22,23,25} square lattice^{17,18} Kagome lattice,^{15,16,24} *etc.* The Shastry–Sutherland (SS) lattice is a special type of distorted square lattice introduced by Shastry and Sutherland²⁶ in 1981, and the typical materials are SrCu₂(BO₃)₂ (ref. 27–30) and rare-earth-metal tetraborides RB₄ (R = La–Lu),^{31,32} which have been drawing wide attention, especially on the magnetic order and fractional magnetization plateaus^{27–32} at low temperature. Recently, several 2D MOF materials with the SS lattice have also been synthesized, such as Cu-5,5'-bis(4-pyridyl)(2,2'-bipiridine) (PBP)³³ and Fe-PBP.³⁴ Could any other transition metal (TM) elements also form MOFs with PBP? What are the electronic and magnetic properties of this 2D MOF material family with the SS lattice? These questions stimulate us to perform intensive theoretical research on them to extend the frontier of the 2D MOF field.

In this work, the 2D TM-PBP (TM = Cr, Mn, Fe, Co, Ni, Cu, Zn) family of MOFs with the SS lattice has been systematically investigated by means of first-principles density functional theory (DFT) calculations and Monte Carlo simulations. It turns out that they have diverse ground state magnetic properties, *i.e.*, Mn-PBP and Fe-PBP are found to be ferromagnetic (FM) and antiferromagnetic (AFM), while TM-PBP (TM = Cr, Co, Ni) and TM-PBP (TM = Cu, Zn) are found to be magnetic-dimerized and nonmagnetic, respectively. Especially, to the best of our

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knowledge, Mn-PBP should be the first FM 2D MOF with the SS lattice, the Curie temperature of which is predicted to be about 105 K. The novel low-symmetry coordination bonds caused by hybridization of the p_z orbital from PBP molecules and the d_{xz} and d_{yz} orbitals from Mn atoms play a very important role in the formation of TM-PBP. The electronic structure calculations reveal that TM-PBP MOFs are semiconductors with band gaps ranging from 0.12 eV to 0.85 eV, which could be easily modulated by various methods, such as strain or hole/electron doping. A spin-field-effect transistor device model has been proposed and potential applications have been discussed.

Methods

The first-principles calculations were performed using the Vienna *ab initio* simulation package (VASP)³⁵ with the generalized gradient approximation (GGA) of Perdew–Burke–Ernzerhof (PBE)³⁶ for the exchange–correlation potential. The interaction between the electron and nuclei was expressed with the projector-augmented wave (PAW) method.³⁷ The planewave function kinetic energy cutoff is 800 eV and the energy convergence threshold is 10^{-6} eV. The Brillouin zone was sampled with the $5 \times 5 \times 1$ Γ -centred Monkhorst–Pack grid.³⁸ The cell shape and volume were fully optimized and the maximum force for each atom was less than $0.01 \text{ eV } \text{\AA}^{-1}$. Coulomb and exchange interactions of the localized d orbitals in TM elements were treated with the DFT + U method proposed by Dudarev *et al.*,^{39,40} where only the $U_{\text{eff}} = U(\text{correlation energy}) - J(\text{exchange energy})$ value is meaningful. Referring previous work on other 2D MOFs^{15,16,41–43} with the DFT + U method, the same value $U_{\text{eff}} = 3 \text{ eV}$ for TM elements was adopted in our calculations. To confirm the FM ground state of Mn-PBP, we also used the linear response theory developed by Cococcioni^{44,45} to evaluate U_{eff} and the obtained value was 4.2 eV (see Fig. S1†), which does not change the FM ground state of Mn-PBP. Moreover, to further check the effect of the U_{eff} value on magnetic properties, a series of U_{eff} values ranging from 1.0 eV to 4.2 eV have also been tested, and the ground state of Mn-PBP is always FM. Thus, the finding of the FM ground state of Mn-PBP is reliable. During the Monte Carlo simulation, the spins on all sites flip randomly. We employed a 2D 200×200 SS lattice with 10^9 flip steps for each temperature. A test on the 100×100 SS lattice with 10^8 steps was also performed, and almost the same results were obtained, verifying that the simulation converged. More calculation details can be found in the ESI.†

Results and discussion

Fig. 1 shows the schematic structure of the TM-PBP framework and the black dashed lines outline the square unit cell. There are four TM atoms and two PBP molecules in each unit cell, and each TM atom bonds with three N atoms, marked as N1, N2, and N3. Focusing on the TM atoms, which are connected by red dotted lines (nearest neighbor) and blue dashed lines (second-nearest neighbor), the TM-PBP framework can be abstracted to a deformed square lattice and is topologically-equivalent to the standard Shastry–Sutherland (SS) lattice (see Fig. S2†). Table 1

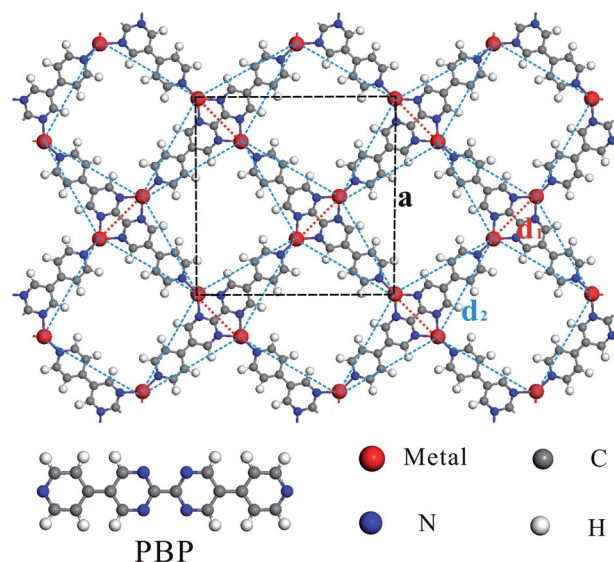


Fig. 1 Schematic atomic structure of TM-PBP. The black dashed lines outline the unit cell of the TM-PBP system and the lattice parameter is marked as a . N1, N2 and N3 indicate the three N atoms (blue balls) surrounding one TM atom (red ball). The red dotted lines (d_1) and blue dashed lines (d_2) represent the interactions between the nearest TM atoms and the second nearest TM atoms, respectively.

lists the lattice parameters of TM-PBP, which generally decrease from Cr to Zn as the atomic numbers increase except Cu. The nearest neighboring TM atom distances (d_1) are approximately 5–6 Å, while the second-nearest neighboring TM atom distances (d_2) are about 10 Å. The binding energy between TM atoms and PBP molecules is generally about 3–4 eV per TM atom for most TM-PBP MOFs except that of Zn-PBP is only 1 eV. Detailed geometric parameters of TM-PBP are listed in Table S1.†

To identify the magnetic ground states of 2D TM-PBP frameworks, three different typical magnetic state configurations, *i.e.*, FM, Néel AFM and stripe AFM (see Fig. S2†) have been considered and investigated. Significantly, only the Mn-PBP framework is found to hold FM ground states; while Fe-PBP, TM-PBP (TM = Cr, Co, Ni) and TM-PBP (TM = Cu, Zn) are proved to be stripe-order AFM, magnetic-dimerized and nonmagnetic, respectively. To the best of our knowledge, Mn-PBP is the first 2D MOF material with the SS lattice discovered to present the FM ground state. As for the magnetic exchange interactions among TM atoms, considering that the nearest neighboring distances (d_1) are much longer than the second-nearest neighboring distance (d_2), the nearest neighboring magnetic exchange interactions should be much stronger than the second-nearest neighbouring interactions, which leads to complex magnetic states in TM-PBP systems.

Electronic structures of all the above TM-PBP frameworks have been obtained, where the energy bands and projected density of states (PDOS) of Mn-PBP are shown in Fig. 2 and the energy bands of others are shown in Fig. S4.† All of them are found to be semiconductors and the band gaps range from 0.12 eV to 0.85 eV, as listed in Table 1. Cu-PBP has the largest energy gap, while Mn-PBP has the smallest gap. Only Mn-PBP



Table 1 a (Å): lattice parameter; d_1 (Å) and d_2 (Å): distances between the nearest TM atoms and second nearest TM atoms, respectively; E_b (eV): binding energy between TM atoms and PBP molecules; E_g (eV): energy band gap; M (μ_B) and M_{cell} (μ_B per cell): magnetic moment per TM atom and per unit cell, respectively; J_1 (meV) and J_2 (meV): magnetic coupling coefficients for the nearest neighbouring TM atoms and second-nearest neighbouring TM atoms, respectively

	a	d_1	d_2	E_b	E_g	M	M_{cell}	J_1	J_2	Magnetic
Cr	18.17	5.91	10.33	3.4	0.73	4.36	0	0.1	-3.3×10^{-5}	Dimerized
Mn	17.79	5.50	10.21	3.5	0.12	4.33	16	−1.86	−0.31	FM
Fe	17.67	5.43	10.15	4.2	0.16	3.12	0	2.5	0.7	Stripe-order AFM
Co	17.62	5.46	10.11	4.4	0.53	1.96	0	0.4	-3.5×10^{-2}	Dimerized
Ni	17.49	5.33	10.06	4.3	0.73	0.96	0	0.9	-2.0×10^{-2}	Dimerized
Cu	17.55	5.44	10.07	3.6	0.85	0	0	—	—	Nonmagnetic
Zn	17.34	5.17	10.01	1.0	0.13	0	0	—	—	Nonmagnetic

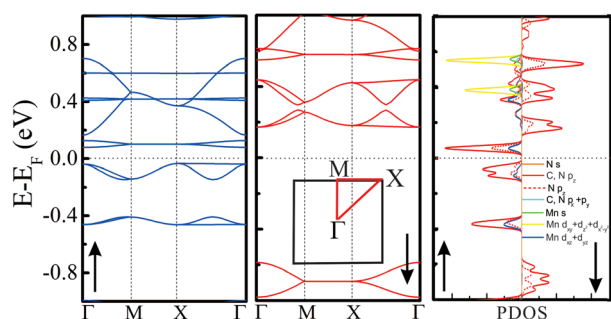


Fig. 2 Electronic structure of Mn-PBP. Left panel: spin-up bands (blue lines); Middle panel: spin-down bands (red lines); Right panel: spin-up and spin-down projected density of states (PDOS).

has the FM ground state, which means that the spin-up and spin-down energy bands deviate from each other. As indicated in Fig. 2, spin-up electrons hold the semiconducting behavior with a band gap of 0.12 eV, while an almost 1 eV band gap is observed for the spin-down electrons. This means that the Mn-PBP framework is a FM semiconductor with a tiny band gap, resulting in that 100% spin-polarized carriers could be obtained under thermal, optical or electrical gating excitation. The calculated PDOS revealed that strong hybridization of p_z orbitals from C and N atoms and the d_{xz} and d_{yz} orbitals from Mn atoms occurs near the Fermi level, while the s , d_{xy} , and d_{z^2} orbitals of Mn atoms are located about 0.4–0.8 eV above the Fermi level and correspond to the flat-band states with higher energy. This phenomenon could be rationalized as follows. As shown in Fig. 3(a), three Mn–N bonds around the same Mn atom do not hold C_3 symmetry. The distance between Mn and N1 atoms is 2.01 Å, while the distance between Mn and N2/N3 atoms is 2.06 Å. The angle of N2–Mn–N3 and N1–Mn–N2 is 83.64° and 138.18°, respectively. The diverse bond lengths and angles reveal that asymmetric Mn–N coordinating bonds are formed. Under the non-equilateral triangle crystal field contributed by neighboring N atoms, the Mn d orbitals split, d_{xz} and d_{yz} orbitals shift down and d_{xy} , d_{z^2} and $d_{x^2-y^2}$ orbitals shift up. The d_{xz} and d_{yz} orbitals of Mn are located around the Fermi level and hybridize with the p_z orbitals of C and N atoms, which is responsible for the bonding between Mn and PBP molecules. The PDOS of Co-PBP and Cu-PBP is drawn in Fig. S5,[†] also

indicating that the DOS near Fermi level mainly comes from the p_z orbital of N/C atoms and the d orbital of TM atoms.

The electronic and spin properties in real space are also investigated. Fig. 3(a) manifests the partial charge density of Mn-PBP around the Fermi level. Consistent with the above deduction that d orbitals (Mn) strongly hybridize with p_z (N and C atoms) orbitals, the partial charge density is mainly located around the Mn atom and its neighboring N atom. Fig. 3(b) shows the spin-polarized charge density of Mn-PBP. It is clear that the majority spin is located on Mn atoms, which should be provided by the d_{xz} and d_{yz} orbitals of Mn. Meanwhile, the minority spin is mainly on PBP molecules. Mn atoms and adjacent N atoms are oppositely polarized, and the polarization of the adjacent N1 atom is much stronger than N2 and N3 atoms. Interestingly, the carbon atoms in PBP molecules are alternately polarized, which is very similar to the phenomena described by the RKKY exchange mechanism.⁴⁶ Similar

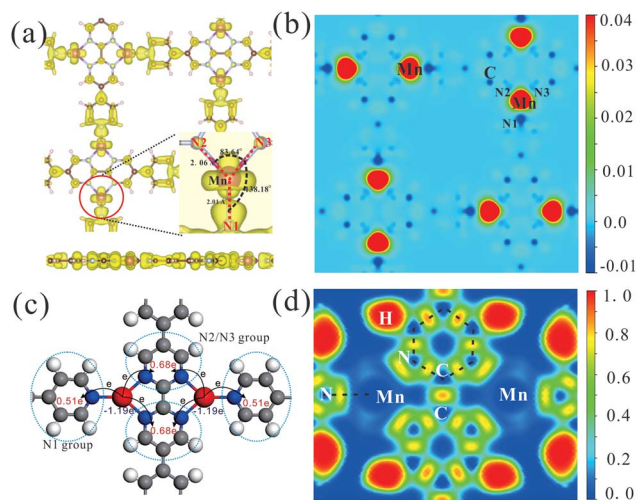
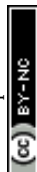


Fig. 3 (a) Top and side views of partial charge density for the Mn-PBP framework. The energy range was chosen as -0.2 to 0.2 eV, and the isosurface value was 0.002 e bohr $^{-3}$. The inset enlarges the area around the Mn atom, where three neighbouring N atoms of Mn were marked as N1, N2 and N3. (b) Spin-polarized charge density of Mn-PBP on the plane crossing all Mn atoms. The scale bar unit is e bohr $^{-3}$. (c) The values of charge transfer from Mn to PBP. (d) The electron localization function of Mn-PBP on the plane crossing all Mn atoms.



phenomena can also be observed in some other MOF materials.¹⁶ Obviously, the spin-polarization on PBP molecules is very weak compared with Mn atoms, showing a FM spin lattice of Mn atoms (Fig. S6†). The spin polarization of the Fe-PBP framework is also investigated and shown in Fig. S6†. The nearest Fe atoms form AFM dimers and the whole framework exhibits stripe AFM order.

By means of Bader charge analysis,^{47,48} migrations of charge in Mn-PBP are obtained and shown in Fig. 3(c). The charge transfer from each Mn atom to whole PBP molecules is evaluated as 1.19e. Besides, the PBP molecules around each Mn atom can be viewed as three groups, *i.e.*, the N1 group and N2/N3 group. Charges transferred from the Mn atom to the N1 group and the N2/N3 group are 0.51e and 0.68e, respectively, where each of the N1 and N2/N3 atoms accepts about 0.13e and 0.12e from nearby Mn atoms respectively. Fig. 3(d) presents the electron localization function (ELF) analysis. A high ELF area is found at C–C and C–N covalent bonds. There is also a large high ELF area between N and Mn atoms, which is apparently different from the C–C bond and should correspond to the N–Mn coordinated bond caused by the electron pair donation from the N atom to the Mn atom. Moreover, a bridge-like area between neighbouring N1, N2 and N3 atoms with low ELF can be observed, which may imply that neighbouring N atoms can interact with each other directly.

To further understand the magnetic properties and mechanism of TM-PBP frameworks, a 2D Ising model for the SS lattice³⁰ is adopted,

$$E_{\text{total}} = E'_0 + E_{\text{mag}} = E'_0 + \sum_{\langle i,j \rangle} J_1 \cdot \vec{u}_i \cdot \vec{u}_j + \sum_{\langle l,m \rangle} J_2 \cdot \vec{u}_l \cdot \vec{u}_m$$

where the E_{mag} and E'_0 represent the energy of magnetic interaction and the total energy without the magnetic interaction respectively. J_1 and J_2 stand for the coupling coefficients of the nearest metal atoms and second nearest metal atoms, $\vec{u}_i(\vec{u}_j)$ and $\vec{u}_l(\vec{u}_m)$ indicate the spin operators at the nearest sites i and j (second nearest sites l and m) respectively. Due to the small value of the magnetic anisotropic energy (~ 0.034 meV, see Section 8 of ESI†), the magnetic anisotropic energy term is neglected.

With the total energy of the TM-PBP framework with different magnetic configurations, the value of coupling coefficients J_1 and J_2 can be acquired (see Section 5 of ESI†), and the results are listed in Table 1. The exchange coupling coefficients of Mn-PBP and Fe-PBP are much larger than those of others. In fact, the values of J_1 and J_2 demonstrate the coupling types for the nearest and second-nearest TM atoms. For Mn-PBP, coupling coefficients J_1 (−1.86 meV) and J_2 (−0.31 meV) are both negative, which shows that the magnetic exchange interactions between the nearest and second-nearest TM atoms are both FM, and the whole system also exhibits FM behavior. For Fe-PBP, J_1 (2.5 meV) and J_2 (0.7 meV) are both positive, implying AFM interactions between neighboring Fe atoms and a stripe AFM ground state of the whole system. For TM-PBP (TM = Cr, Co, Ni), J_1 values are positive, illustrating AFM interactions between the nearest neighboring TM atoms, however, J_2 is lower than J_1 by at least two orders of magnitude. Thus, we deduce that the magnetic

ground state of TM-PBP (TM = Cr, Co, Ni) should be a dimer phase, in which the nearest TM atoms are bonded to AFM dimers, but the whole system doesn't exhibit macro magnetic order. Notably, the SS lattice systems normally display AFM ground states,^{30–32} whereas the FM ground state found in Mn-PBP here contributes a novel example of the FM SS spin lattice.

Based on the above Ising model and exchange coupling coefficients, the thermodynamical magnetic properties for the Mn-PBP framework are simulated using the Monte Carlo method.^{15,49,50} As shown in Fig. 4, the total magnetic moments per unit cell start to drop gradually from 16 μ_B at about 60 K, until at about 110 K the total magnetic movements become 0 μ_B . The second order phase transition point is located at about 105 K, which corresponds to the value of T_c . The effect of U on T_c has been calculated and the detailed results in Fig. S10† indicate that very small changes happen when the different value of U is selected for the calculation. Compared with recent experiments for 2D FM materials, *e.g.* 2D PTC-Fe MOFs⁵¹ and 2D CrI₃,⁵² this material holds a much higher T_c . It is more likely that this result can be verified by experiments, although the Curie temperature could be overestimated from the Ising model.

As mentioned above, Mn-PBP is a FM semiconductor with a tiny band gap, which could be easily regulated by various methods. We have tried to apply strain on Mn-PBP, and it is uncovered that 95% compressive strain could turn Mn-PBP into a half metal (see Fig. S11†), which can act as a spin filter to obtain 100% spin-polarized carriers. The strain will also change the distance between Mn atoms and affect the exchange coupling coefficients, and thus would change the Curie temperature. As shown in Fig. 4, a 95% compressive strain will raise the Curie temperature from 105 K to 125 K. Furthermore, electron and hole doping can also increase the Curie temperature as shown in the inset of Fig. 4.

The effect of electron and hole doping on the electronic structure of Mn-PBP is investigated and shown in Fig. 5. Since

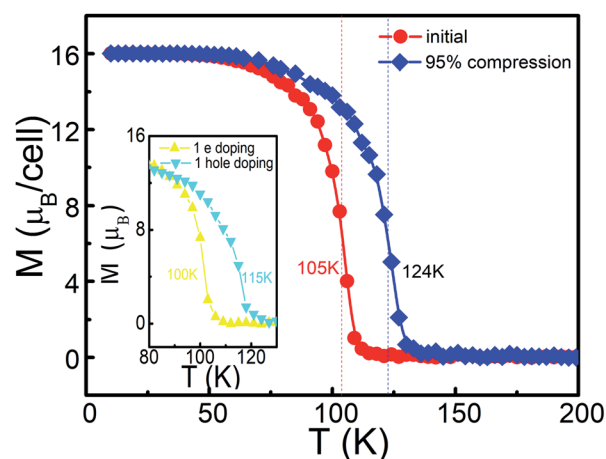


Fig. 4 The variation of the average magnetic moment of the unit cell with respect to the temperature for Mn-PBP, the red and blue lines correspond to the optimized and 95% biaxial compression, respectively, and the left inset indicates the phenomenon when 1 electron/hole in each unit cell was doped.



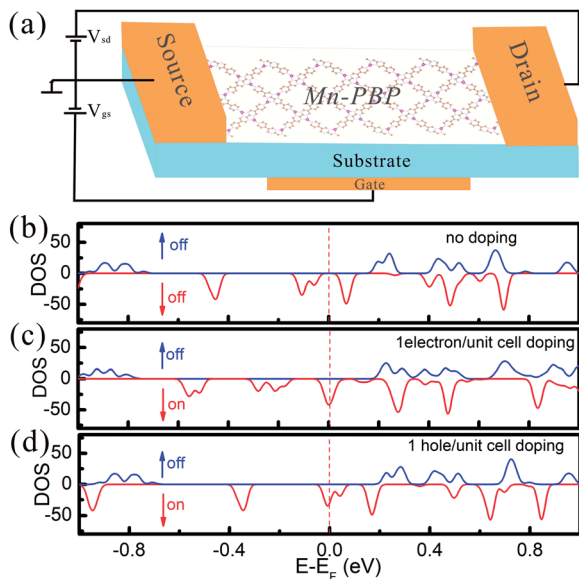


Fig. 5 (a) The schematic of a spin-field-effect transistor device based on Mn-PBP. (b) The total DOS of spin-up and spin-down electrons without electron/hole doping. The total spin-up and spin-down DOS of Mn-PBP with (c) one electron or (d) one hole doped per unit cell.

the band gap is tiny and there are spin-polarized states below and above the Fermi level, when the system is doped with 1 hole/electron per unit cell, the Fermi level declines/inclines and crosses the spin-polarized energy band, giving rise to a half metal in which spin-up electrons behave as a metal, while spin-down electrons act like a semiconductor. According to this analysis, we proposed a spin-field-effect transistor (SFET) based on Mn-PBP, and its schematic structure is declared in Fig. 5(a). Since electron/hole doping can be controlled by the substrate materials and gate voltage V_{gs} , controllable spin ON/OFF switch can be realized in Mn-PBP SFET and 100% spin-polarization carriers could be observed. Although the concept of SFET was introduced more than two decades ago,⁵³ it is still complicated to realize the functional SFET for information processing. Thus, Mn-PBP is a promising material for future spintronic devices.

Conclusions

A family of 2D TM-PBP MOFs with the SS lattice has been systematically studied by means of first-principles calculations and Monte Carlo simulations. In the TM-PBP framework, each TM atom bonds with its nearby three N atoms with asymmetric coordination bonds. Different magnetic arrangements have been investigated in TM-PBP frameworks, where the Mn-PBP framework holds the FM ground state with a Curie temperature of about 105 K, Fe-PBP possesses the stripe AFM ground state, TM-PBP (TM = Cr, Co, Ni) forms the magnetic dimerized ground state, and TM-PBP MOFs (TM = Cu, Zn) are non-magnetic. Their band gap ranges from 0.12 eV to 0.87 eV. The Mn-PBP framework is found to be a half semiconductor with a band gap of less than 0.15 eV, caused by the novel low-symmetry coordination bonds with the hybridization of the p_z

orbital from PBP molecules and the d_{xz} and d_{yz} orbitals from Mn atoms. Especially, it is demonstrated that strain will cause Mn-PBP to transit from semiconductor to metal. Furthermore, electron doping and hole doping of Mn-PBP are investigated, illustrating that the Mn-PBP framework can be easily regulated from half semiconductor to half-metal. As Cu-PBP and Fe-PBP systems have been already successfully synthesized, it is promising that Mn-PBP and other 2D MOFs TM-PBP we studied here can also be synthesized in the near future. These novel properties indicate that TM-PBP frameworks have promising applications in electronic devices, especially the Mn-PBP framework with the first predicted FM ground state with the SS lattice in MOFs is an excellent 2D candidate material for spintronic application.

Conflicts of interest

There are no conflicts to declare.

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